



Class	Subclass	ISSUE CLASSIFICATION

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PATENT NUMBER

U.S. UTILITY Patent Application

O.I.P.E.

PATENT DATE

AK
SCANNED #16m3 O.A. #103

APPLICATION NO. 09/955600	CONT/PRIOR D F	CLASS 438	SUBCLASS 	ART UNIT 2813	EXAMINER Tuan Nguyen
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APPLICANTS

Nobuhiko Hayashi
Takashi Kano

TITLE

Semiconductor device and method of fabricating the same and method of forming nitride based semiconductor layer

PTO-2040
12/99

ISSUING CLASSIFICATION

ORIGINAL		CROSS REFERENCE(S)					
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)				
INTERNATIONAL CLASSIFICATION							

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<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
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<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____	_____ (Primary Examiner)			ISSUE FEE	
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